Exp. No.:

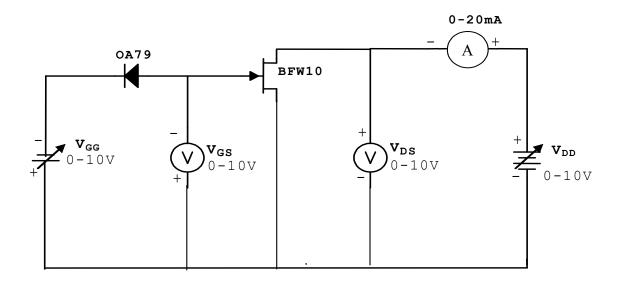
FET CHARACTERISTICS

AIM : To obtain the Drain and Transfer characteristics of JFET and also determine Transconductance(g_m), drain resistance(r_d) and amplification factor(μ).

APPARATUS:

S.No.	Name of the Apparatus	Range	Quantity
1.	BFW10, OA79	-	Each 1No.
2.	Power Supply	0-30V	2No.
3.	Ammeter	0-20mA	1No.
4.	Voltmeter	0-10V	2No.

CIRCUIT DIAGRAM:



PROCEDURE:

Drain Characteristics:

- 1. Connect the circuit as shown in figure.
- 2. Keep V_{GS} = 0, Vary V_{DD} and note down V_{DS} and I_{D} .
- 3. Repeat the above step for V_{GS} = -1v and -2v.
- 4. Draw the drain characteristics by taking V_{DS} on X-axis and I_{D} on Y-axis

Exp. No.:

Transfer Characteristics:

- 5. Fix V_{DS} at 2V, vary V_{GG} and note down V_{GS} and $I_{\text{D}}.$
- 6. Repeat the above step for $V_{DS} = 4V$.
- 7. Plot the transfer characteristics by taking V_{GS} on X-axis and I_{D} on Y-axis.

READINGS:

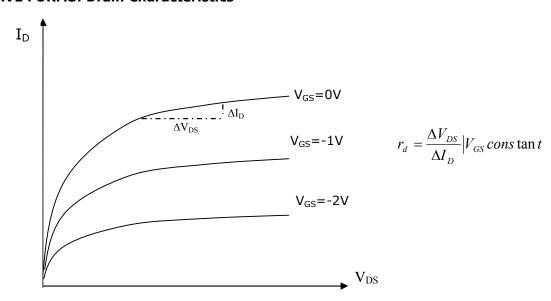
a. Drain Characteristics:

V _{GS} =OV		V _{GS} = -1V		V _{GS} = -2V	
V _{DS} (V)	I _D (mA)	V _{DS} (V)	I_D (mA)	V _{DS} (V)	I _D (mA)

b. Transfer Characteristics:

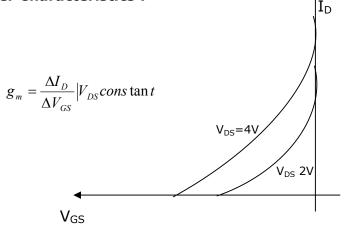
V _{DS} =2V		V _{DS} =4V		
V _{GS} (V)	I _D (mA)	V _{GS} (V)	I _D (mA)	

MODEL WAVE FORMS: Drain Characteristics



Exp. No.:

Transfer Characteristics:



$$r_d = \frac{\Delta V_{DS}}{\Delta I_D} \bigg|_{V_{GS}Cons \tan t} =$$

$$g_{m} = \frac{\Delta I_{D}}{\Delta V_{GS}} \bigg|_{V_{DS}Cons \tan t} =$$

Amplification factor (μ) = $g_m.r_d$ =

RESULTS:

- 1. Transconductance $(g_m)=$
- 2. Drain Resistance (r_d)=
- 3. Amplification Factor (μ) =